

# DTS6014 0.1 TO 6.0 GHz THRESHOLD DETECTOR

Typical Values @ +25 °C

<b>Wide Frequency Range</b> .....	<b>0.05 to 8.0 GHz</b>
<b>Wide Power Range</b> .....	<b>-12.0 to +12.0 dBm</b>
<b>Fast Response Time</b> .....	<b>800 ηsec</b>
<b>TTL Output Compatibility</b>	
<b>External Adjustable Threshold Level, Low Drift</b>	
<b>Standard SMT0-8 Package</b>	

**DTS6014**

## SPECIFICATIONS\*

Parameter	Typical	Guaranteed	
		0 to 50 °C	-55 to +85 °C
Frequency (Min.)	0.05-8.0 GHz	0.1-6.0 GHz	0.1-6.0 GHz
Input Power Range (Min.)	-12 to +12 dBm	-10 to +10 dBm	-10 to +10 dBm
VSWR (Max.)	1.5:1	2.0:1	2.0:1
Power Flatness (Max.)	±0.5 dB	±0.75 dB	±0.75 dB
Threshold Temperature Stability (Max.) @ -10 dBm Input Power	±0.75 dB	±1.0 dB	±1.0 dB
@ 0 dBm Input Power	±0.5 dB	±0.75 dB	±1.0 dB
@ +10 dBm Input Power	±0.3 dB	±0.6 dB	±0.75 dB
Pulse Response (Max.)			
Rise Time (10% DC to 90% DC)	360 ηsec <sup>^</sup>	700 ηsec <sup>^</sup>	1000 ηsec <sup>^</sup>
Fall Time (90% DC to 10% DC)	65 ηsec <sup>^</sup>	150 ηsec <sup>^</sup>	200 ηsec <sup>^</sup>
Total Response Time (50% RF to 10% or 90% DC)	800 ηsec <sup>^</sup>	1500 ηsec <sup>^</sup>	2000 ηsec <sup>^</sup>
Supply Current (Max.) (no RF)	2 mA	4 mA	5 mA
Supply Current (Max.) (Pin = +5.0 dBm)	2 mA	4 mA	5 mA
Threshold Hysteresis @ -10 to -1 dBm Input Power	±1.0 dB†	±1.5 dB†	±2.0 dB†
@ 0 to +10 dBm Input Power	±0.3 dB†	±1.0 dB†	±1.5 dB†
Control Terminate Current (Max.)	0.3 mA	1.0 mA	1.0 mA
Output Compatibility	TTL	TTL	TTL

\*Measured in a 50 Ohm system at +5.0 Vdc. R<sub>TH</sub>=120 to 2800 Ohm unless otherwise specified. 1 MOhm || 8pF output load. <sup>^</sup> Input change ≥3 dBm above P threshold and applied for entire dynamic range. † Apply for both resistance and voltage control.

## MAXIMUM RATINGS

<b>DC Voltage</b> .....	<b>+20 V</b>
<b>Continuous RF Input Power</b> .....	<b>+20.0 dBm</b>
<b>Operating Case Temperature</b> .....	<b>-55 °C to +125 °C</b>
<b>Storage Temperature</b> .....	<b>-65 °C to +150 °C</b>
<b>Burn-In Temperature</b> .....	<b>+150 °C</b>
<b>Detector Thermal Resistance<sup>1</sup> (θjc)</b> .....	<b>+800 °C/Watt</b>
<b>Temperature Rise @ 10 dBm (Tjc)</b> .....	<b>+8 °C</b>

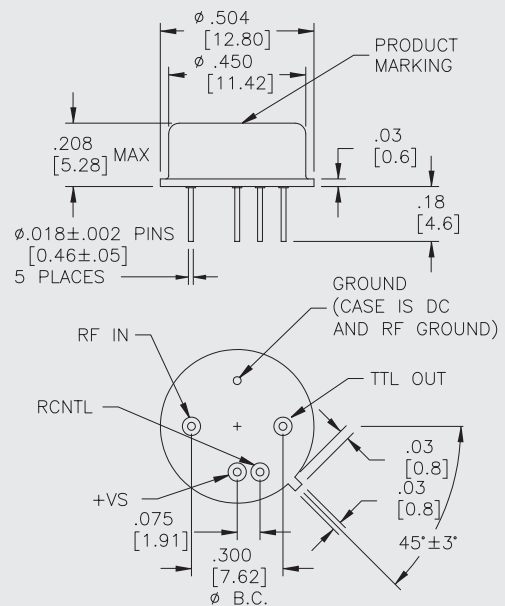
<sup>1</sup> Thermal resistance is based on RF input power. Ratings based on +25 °C.

## APPLICATION NOTES

- ✦ DTS6014 is a sensitive microwave threshold detector which provides efficient and accurate RF level measurement.
- ✦ DTS6014 is configured using two Schottky diode detectors, high precision comparator, and a compensated voltage reference to provide excellent temperature stability.
- ✦ DTS6014 is specifically designed for system built-in test and channel RF activity monitoring.
- ✦ The output of this unit is derived from a comparator, a true TTL logic device.
- ✦ Average power detection is obtained at power levels below approximately 0 dBm.
- ✦ DTS6014 contains open-collector comparator with internal 5.1 KOhm pull-up resistor. Pulse response (Low-to-Hi state) can be sped up by using external pull-up resistor. Max sink current is 6.0 mA.
- ✦ Connect external threshold resistor from Rcntl port to ground.

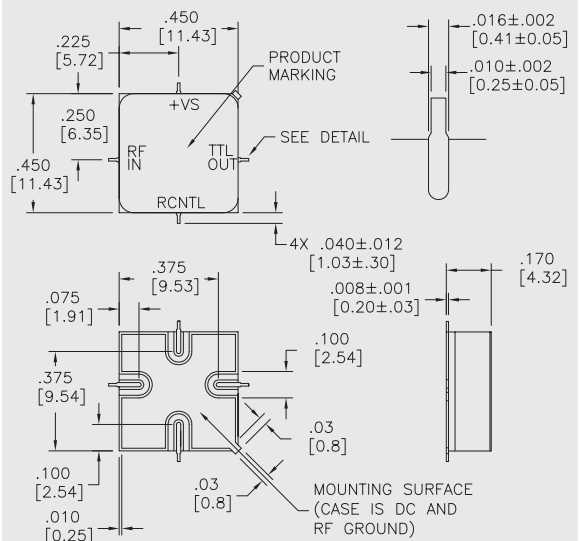
## DTC6014

TO-8 Package for Detectors



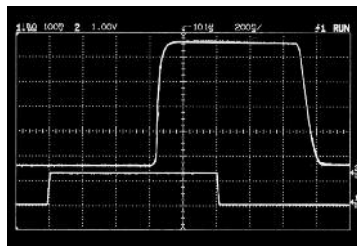
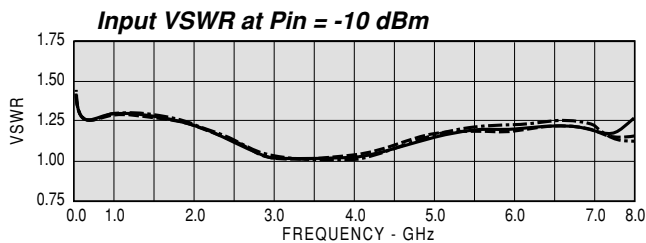
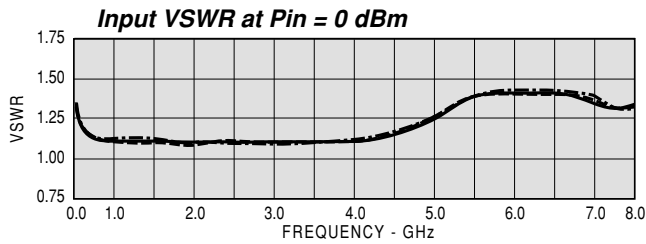
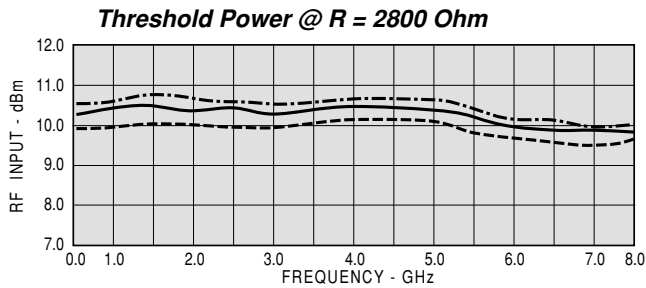
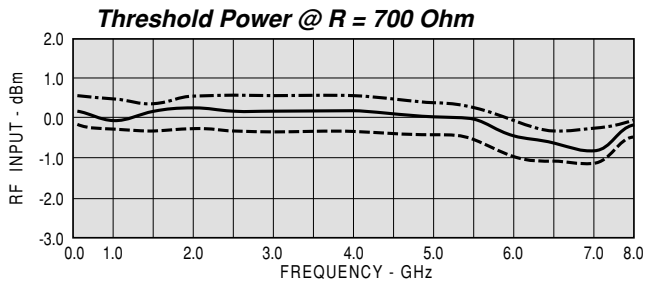
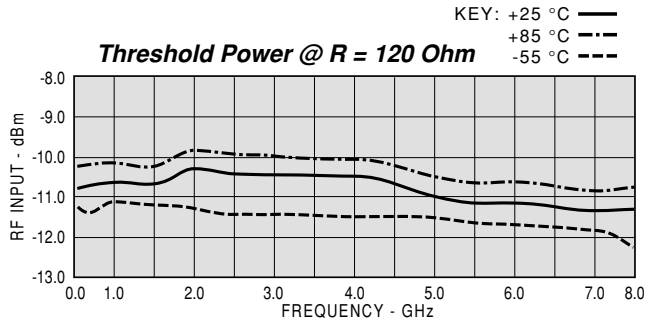
## DTS6014

SMT0-8 for Detectors

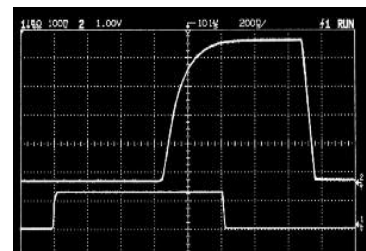
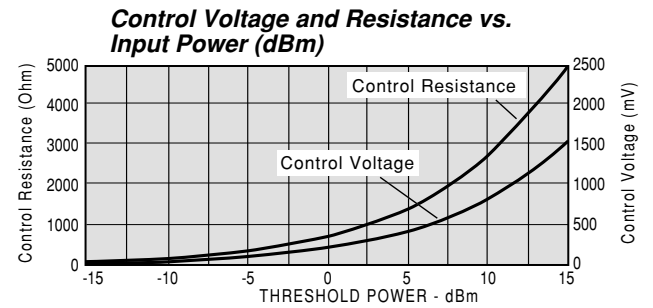
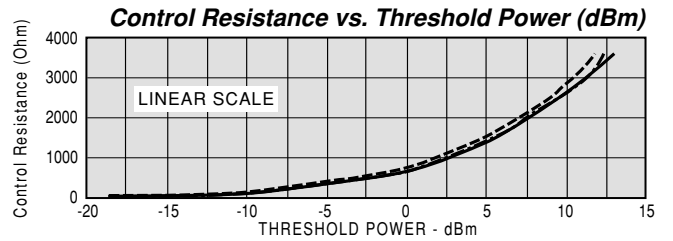
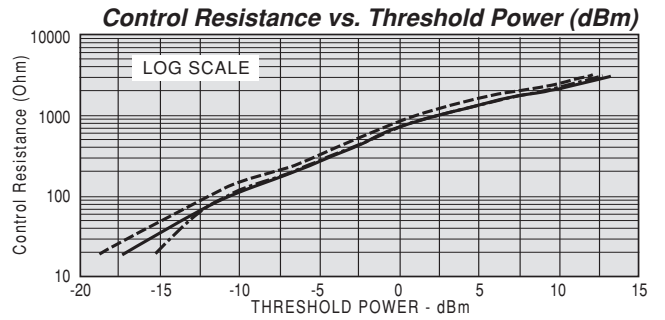


DIMENSIONS ARE IN INCHES [MILLIMETERS]

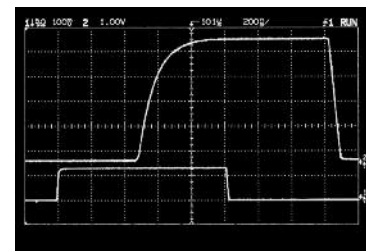
**TYPICAL PERFORMANCE**



Pulse Response @  $R_{TH} = 120$  Ohms  
(with 1KOhm Pull-up Resistor)



Pulse Response @  $R_{TH} = 120$  Ohms



Pulse Response @  $R_{TH} = 2800$  Ohms

Top Trace: TTL Logic Out  
Bottom Trace: RF Input  
Time Base: 200 ns/div